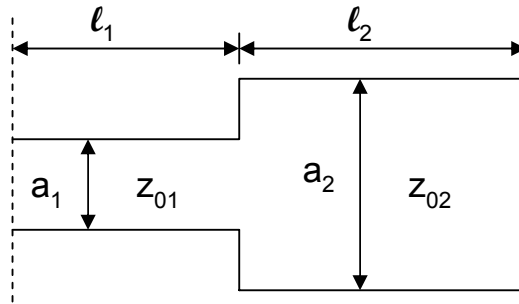


Microwave Physics and Techniques

Solutions to Final Exam – June 20, 2003

Problem 1.



$$Z_{01} = a_1 \sqrt{\mu/\epsilon}$$

$$Z_{02} = a_2 \sqrt{\mu/\epsilon}$$

For open CKT load:

$$Z_1 = -jZ_{01} \cot\left(\frac{\omega l_1}{v_1}\right)$$

For short CKT load:

$$Z_2 = -jZ_{02} \tan\left(\frac{\omega l_2}{v_2}\right)$$

$$v_1 = v_2 = \frac{1}{\sqrt{\mu\epsilon}} (= c \text{ in air})$$

For transverse resonance $Z_1 + Z_2 = 0$

$$\Rightarrow jZ_{01} \tan \frac{2\pi l_1}{c} + jZ_{02} \tan \frac{2\pi l_2}{c} = 0$$

$$l_1 = 0.075 \text{ m}, l_2 = 0.05 \text{ m}, a_1 = 0.01 \text{ cm}, a_2 = 0.05 \text{ cm}$$

$$\Rightarrow (0.01) \frac{\cot 2\pi f(0.075)}{3 \times 10^8} + (0.05) \frac{\tan 3\pi f(0.05)}{3 \times 10^8} = 0$$


$$\Rightarrow \text{cutoff frequency : } f_c = 326.21 \text{ MHz}$$

Problem 1. Cont.

$$\lambda_g = \frac{\lambda}{\sqrt{1 - (\lambda/\lambda_0)^2}}$$

In the 5m long chamber, $\lambda_g=10\text{m}$, $\lambda_{g2}=5\text{m}$, $\lambda_{g3}=3.33\text{m}$, $\lambda_{g4}=2.5\text{m}$, ...

$\lambda_c=0.9197\text{m}$


Freq (MHz)	B.C. λ_g (cm)	Rect WG	$\lambda_{\text{free space}}$ (cm)
327.6	1.0	 <p>Below cutoff $\lambda_c = 2a = 0.5 \text{ m}$ $f_c = 600 \text{ MHz}$</p>	0.9158
331.7	5.0		0.9045
338.4	3.33		0.8866
347.6	2.5		0.8631
359	2.0		0.8356

Conductor loss or power dissipation is

$$P_l = \iint R_s |H|^2 ds$$

Without NEG strips, $P_l \approx R_s S$ where R_s is the surface resistance of the aluminum and S is the surface area of the two square chambers. With NEG strips

$$P_l \approx R_s S + R_s \left(\frac{S}{2} \right) \sqrt{10} \cdot 2$$


 two sides of NEG

$$P_l \approx 4.2 R_s S$$

Problem 2.

$$a) S_{12} \neq S_{21} \Rightarrow \text{not reciprocal}$$

$$b) \begin{bmatrix} S_{11} & S_{12} \\ S_{21} & S_{22} \end{bmatrix} \begin{bmatrix} S_{11}^* & S_{21}^* \\ S_{12}^* & S_{22}^* \end{bmatrix} = \begin{bmatrix} 1 & 0 \\ 0 & 1 \end{bmatrix}$$

$$\Rightarrow S_{11}S_{21}^* + S_{12}S_{22}^* = j + 1 \neq 0 \text{ Not lossless}$$

Problem 3.

$$\omega_0 = \frac{1}{\sqrt{LC}} = 10^9 \text{ rad/s}$$

$$Q_u = \frac{1}{\omega_0 RC} = \frac{\sqrt{LC}}{RC} \approx 6667$$

$$Q_e = \frac{1}{\omega_0 R_L C} = 2000$$

$$Q_L = \left[\frac{1}{Q_L} + \frac{1}{Q_e} \right]^{-1} \approx 1538$$

$$\kappa = \frac{Q_u}{Q_e} = \frac{R_C}{R} = \frac{50}{15} \approx 3.33$$

Problem 4.

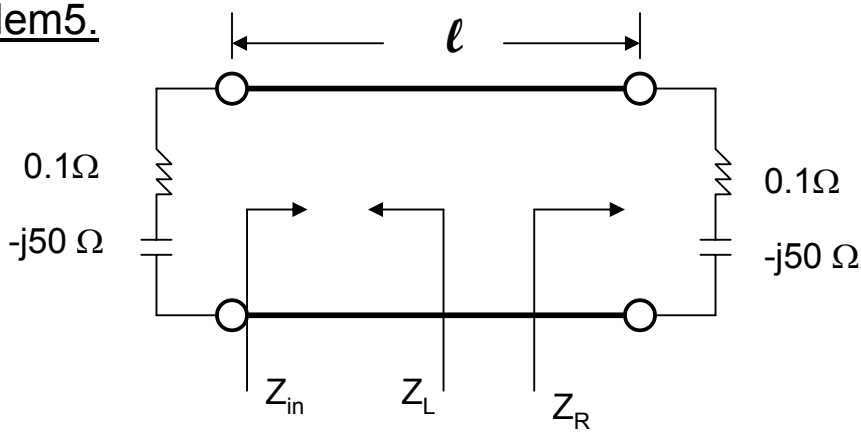
$$f_{cTE_{11}} \approx \frac{1.8412c}{2\pi a} \leq 0.8(6.8) \text{ GHz} \Rightarrow a_{min} \approx 1.717 \text{ cm}$$

$$f_{cTE_{01}} \approx \frac{3.82c}{2\pi a} \geq 1.1(6.4) \text{ GHz} \Rightarrow a_{max} \approx 2.6 \text{ cm}$$

∴ The waveguide radius must lie in the range $1.771 \leq a \leq 2.6$ cm. But since the criteria is to maximize the power delivering capability of the waveguide, we choose $a = a_{max} \approx 2.6$ cm.



Problem 5.



Since the resonator is symmetric at the midpoint of the line, we must have

$$Z_L = Z_R^* = Z_R \quad \text{or} \quad \Im m\{Z_R\} = 0$$

Let $t = \tan \beta \ell / 2$ and $Z_L = R_L + jX_L$ ($R_L = 0.1 \Omega$, $X_L = -50$)

$$\begin{aligned} Z_R &= Z_0 \frac{Z_L + jZ_0 t}{Z_L + jZ_L t} = Z_0 \frac{R_L + j(X_L + Z_0 t)}{(Z_0 - X_L t) + jR_L t} \\ &= Z_0 \frac{R_L(Z_0 - X_L t) + jR_L(X_L + Z_0 t) + j(X_L + Z_0 t)(Z_0 - X_L t) - jR_L^2 t}{(Z_0 - X_L t)^2 + (R_L t)^2} \end{aligned}$$

$$\Im m\{Z_R\} = 0$$

$$\Rightarrow (X_L + Z_0 t)(Z_0 - X_L t) - R_L^2 t = 0$$

$$-X_L Z_0 t^2 + (Z_0^2 - X_L^2 - R_L^2)t + Z_0 X_L = 0$$

$$5000t^2 + 7500t - 5000 = 0 \Rightarrow t^2 + 1.5t - 1 = 0$$

$$\Rightarrow t = 0.5 \quad \text{and} \quad t = -2.0$$

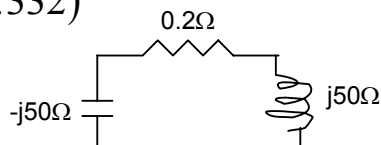
$$\Rightarrow \omega \ell = 53.1^\circ \quad (t = 0.5)$$

$$\omega \ell = -126.9^\circ = 53.1^\circ \quad (t = -2.0)$$

$$\ell = \frac{53.1}{360} \lambda = 0.148 \lambda \Rightarrow \tan \beta \ell = 1.332$$

$$\text{check: } Z_{in} = 100 \frac{(0.1 - j50) + j133.2}{100 + j(0.1 - j50)(1.332)} = 0.1 + j50 \Omega$$

$$Q = \frac{\omega_0 L}{R} = \frac{X_L}{R} = \frac{50}{0.2} = 250.$$



Problem6.

Use

$$\delta = \sqrt{\frac{2}{\omega\mu_0\sigma}}$$

$$R_s = \sqrt{\frac{\omega\mu_0}{2\sigma}}$$

$$\omega = 2\pi \times 10^6, \mu_0 = 4\pi \times 10^{-7}, \sigma = 5.8 \times 10^7$$

$$1\text{MHz} \rightarrow \delta = 66\mu\text{m}, R_s = 2609\mu\Omega / \text{s}$$

@100MHz \rightarrow reduced by factor 10

Surface Resistance \rightarrow increased by 10

And so on...